**Product data sheet** 

## 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- · Logic-level compatible
- Trench MOSFET technology
- Ultra low Q<sub>G</sub> and Q<sub>GD</sub> for high system efficiency, especially at higher switching frequencies
- · Superfast switching with soft-recovery
- · Low spiking and ringing for low EMI designs
- MLPAK33 package (3.3 x 3.3 mm footprint)

### 3. Applications

- DC to DC conversion
- · Battery management
- · Low-side load switch
- Switching circuits

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	30	V
$V_{GS}$	gate-source voltage			-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-	18.3	А
Static characte	eristics						
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 11.4 A; T <sub>j</sub> = 25 °C		-	7.1	8.3	mΩ
		$V_{GS} = 4.5 \text{ V}; I_D = 9.8 \text{ A}; T_j = 25 ^{\circ}\text{C}$		-	8.9	11.1	mΩ
Dynamic chara	acteristics						
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 15 V; $I_{D}$ = 9.8 A; $V_{GS}$ = 4.5 V; $T_{j}$ = 25 °C		-	5.1	7.7	nC

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source	ر ف ف ف	
3	S	source		D —
4	G	gate	]	
5	D	drain		G—UFIA)
6	D	drain	Laaad	mbb076 S
7	D	drain	8 7 6 5 MI DAK22 (SOT9002 4)	
8	D	drain	MLPAK33 (SOT8002-1)	

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package						
	Name	Description	Version				
PXN8R3-30QL		plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1				

## 7. Marking

#### **Table 4. Marking codes**

Type number	Marking code
PXN8R3-30QL	9AD

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	30	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	18.3	Α
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	11.4	Α
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 100 °C	[1]	-	7.2	Α
		V <sub>GS</sub> = 10 V; T <sub>sp</sub> = 25 °C		-	31	Α
I <sub>DM</sub>	peak drain current	T <sub>amb</sub> = 25 °C; single pulse; t <sub>p</sub> ≤ 10 μs		-	293	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	4.3	W
			[1]	-	1.7	W
		T <sub>sp</sub> = 25 °C		-	12.5	W
T <sub>j</sub>	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drain	n diode		'			
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	1.5	Α
Avalanche r	uggedness			1		
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	T <sub>j(init)</sub> = 25 °C; I <sub>D</sub> = 1.7 A; DUT in avalanche (unclamped)		-	25	mJ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

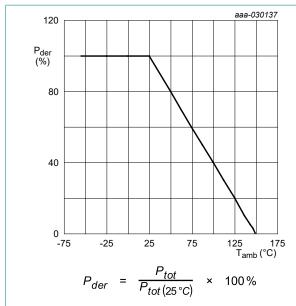


Fig. 1. Normalized total power dissipation as a function of ambient temperature

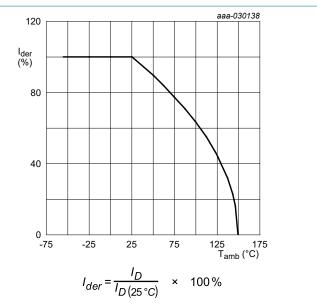


Fig. 2. Normalized continuous drain current as a function of ambient temperature

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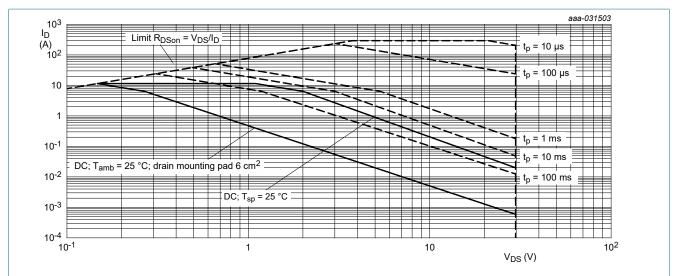


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1]	-	150	190	K/W
	junction to ambient		[2]	-	60	75	K/W
		in free air; t ≤ 5 s	[2]	-	24	29	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	7	10	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

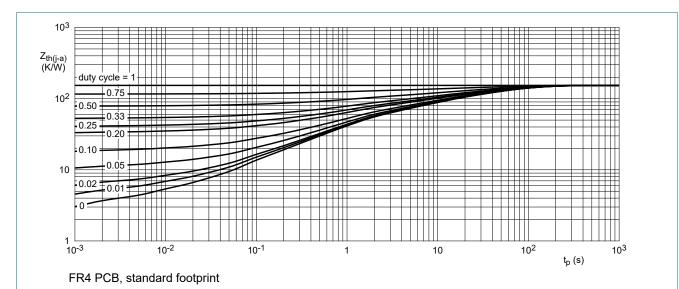


Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

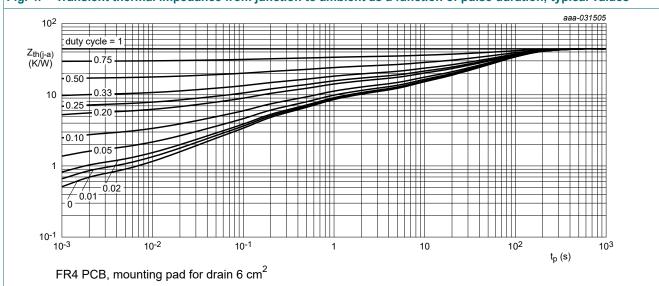


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### 10. Characteristics

#### Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		l e			
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	30	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.7	2.2	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	0.1	μΑ
		$V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-0.1	μΑ
R <sub>DSon</sub>	drain-source on-state	$V_{GS} = 10 \text{ V}; I_D = 11.4 \text{ A}; T_j = 25 \text{ °C}$	-	7.1	8.3	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 11.4 A; T <sub>j</sub> = 150 °C	-	11	12.9	mΩ
		$V_{GS} = 4.5 \text{ V}; I_D = 9.8 \text{ A}; T_j = 25 \text{ °C}$	-	8.9	11.1	mΩ
g <sub>fs</sub>	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 11.4 \text{ A}; T_j = 25 \text{ °C}$	-	25	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	2.3	-	Ω
Dynamic ch	naracteristics					
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 15 V; $I_{D}$ = 11.4 A; $V_{GS}$ = 10 V; $I_{j}$ = 25 °C	-	10.6	15.9	nC
		$V_{DS} = 15 \text{ V}; I_D = 9.8 \text{ A}; V_{GS} = 4.5 \text{ V};$	-	5.1	7.7	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1.9	-	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge		-	1.2	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge		-	0.7	-	nC
Q <sub>GD</sub>	gate-drain charge		-	1.3	-	nC
$V_{GSpl}$	gate-source plateau voltage	V <sub>DS</sub> = 15 V; I <sub>D</sub> = 9.8 A; T <sub>j</sub> = 25 °C	-	2.6	-	V
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 15 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	760	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	270	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	42	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 15 V; I <sub>D</sub> = 9.8 A; V <sub>GS</sub> = 4.5 V;	-	5	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	8	-	ns
$t_{d(off)}$	turn-off delay time		-	6	-	ns
t <sub>f</sub>	fall time		-	3	-	ns
Source-dra	in diode		'			
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 1.5 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.7	1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 1.5 A; dI <sub>S</sub> /dt = -100 A/μs;	-	15	-	ns
Q <sub>r</sub>	recovered charge	$V_{GS} = 4.5 \text{ V}; V_{DS} = 15 \text{ V}; T_j = 25 \text{ °C}$	-	6	-	nC
t <sub>a</sub>	reverse recovery rise time		-	8	-	ns
t <sub>b</sub>	reverse recovery fall time	1	-	7	-	ns

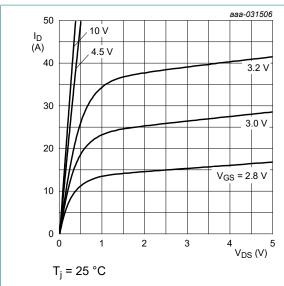


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

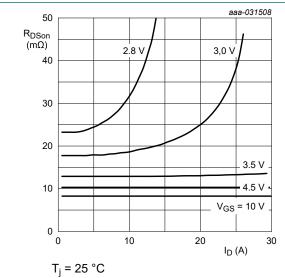


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

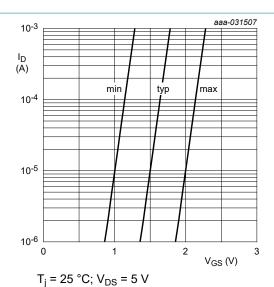


Fig. 7. Subthreshold drain current as a function of gate-source voltage

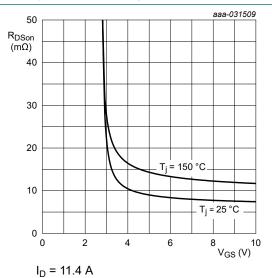


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

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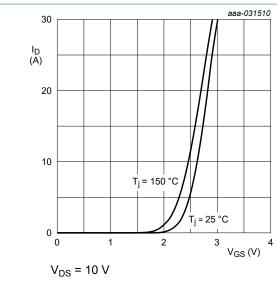


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

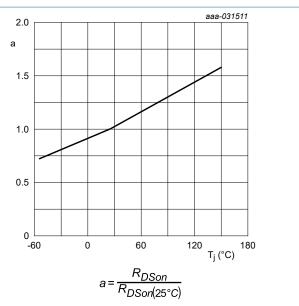


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

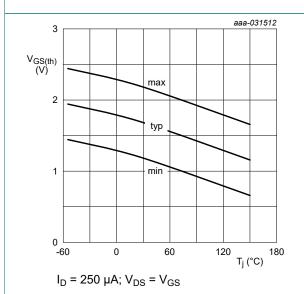
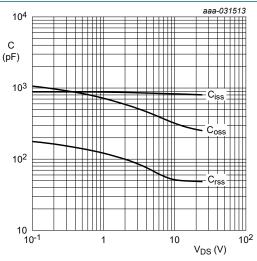


Fig. 12. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$ 

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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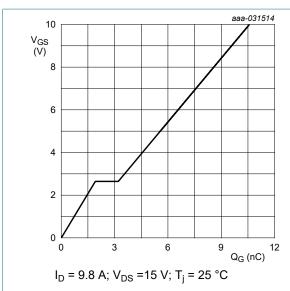


Fig. 14. Gate-source voltage as a function of gate charge; typical values

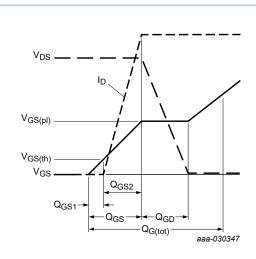


Fig. 15. Gate charge waveform definitions

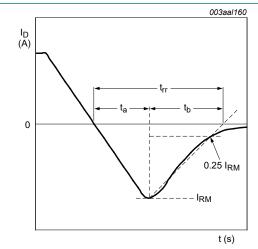


Fig. 16. Reverse recovery timing definition

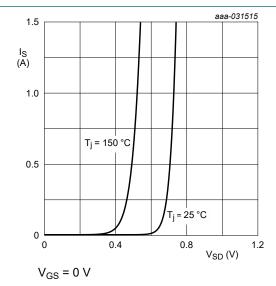
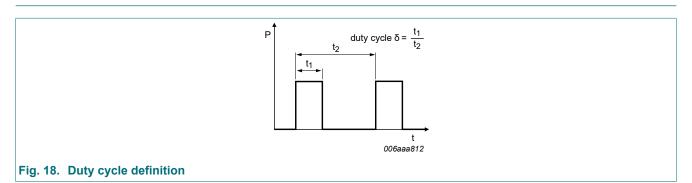


Fig. 17. Source current as a function of source-drain voltage; typical values

### 11. Test information



PXN8R3-30QL

## 12. Package outline

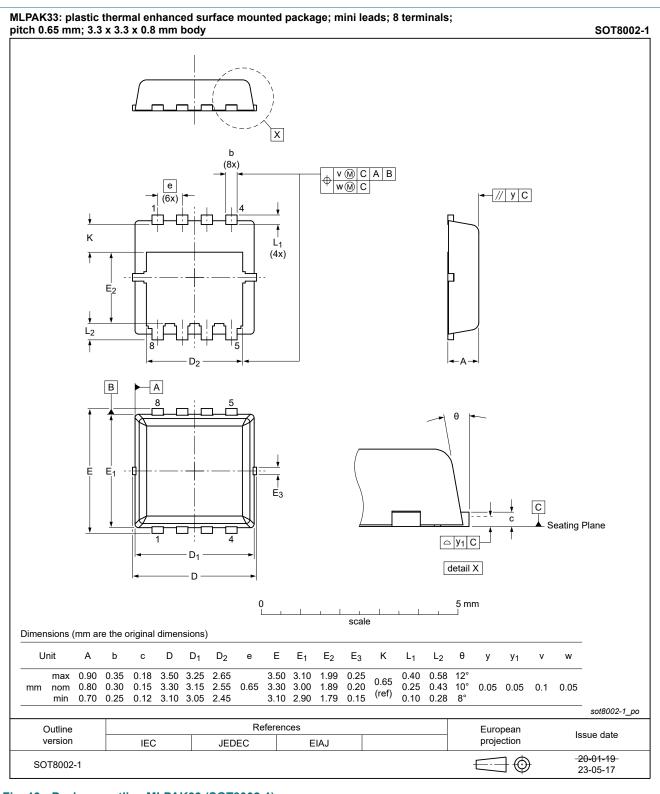
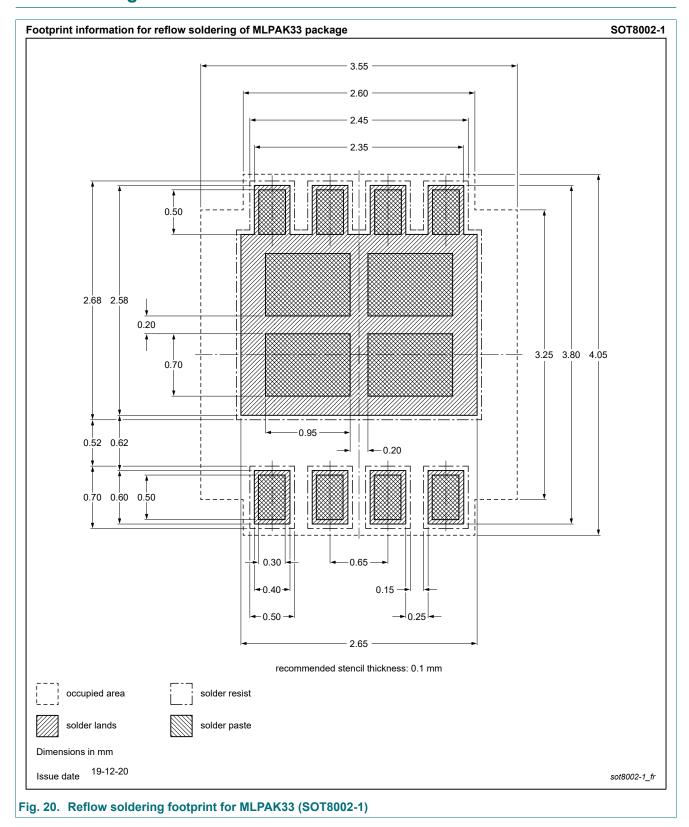


Fig. 19. Package outline MLPAK33 (SOT8002-1)

## 13. Soldering



30 V, N-channel Trench MOSFET

# 14. Revision history

#### **Table 8. Revision history**

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PXN8R3-30QL v.3	20230731	Product data sheet	-	PXN8R3-30QL v.2			
Modifications:	Chapter "Package or	Chapter "Package outline": drawing update					
PXN8R3-30QL v.2	20201102	Product data sheet	-	PXN8R3-30QL v.1			
PXN8R3-30QL v.1	20200428	Preliminary data sheet	-	-			

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PXN8R3-30QL

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